

Table B.1. Peak positions and associated vibrational modes for H-related defects in diamond from first-principals density functional simulations of IR spectra from selected studies.

Frequency (cm ⁻¹)	Defect	Mode (x)	H/Ah	Intensity (km/mol)	S	Functional	Cell	Basis set	Comment	Ref.
412	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 24 neighboring atoms MP 4x4x4 mesh	[1]
422	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes first 24 neighboring atoms MP 2x2x2 mesh	[1]
446	VNH ₃	C-H _b (d)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
451	VNH ₃	C-H _b (c)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling 2-fold degenerate	[2]
471	VN ₂ H ₂	C-H _b (d)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
476	VNH ₂	C-H _b (d)	H	4 (0.6%)	1/2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
494	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 12 neighboring atoms MP 4x4x4 mesh	[1]
496	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes first 12 neighboring atoms MP 2x2x2 mesh	[1]
749	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 2x2x2 mesh	[1]
750	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 4x4x4 mesh	[1]

853	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]
861	VH ₄	C-H _b (c)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]
972	NH ₁	C-H _b	H	-	-	LDF*	64	Gaussian	¹² C-D isotopes Atom and bond centered basis sets	[3]
1296	VN ₃ H	C-H _b	H	-	0	LDA*	216	Gaussian (<i>atom centered</i>)	Basis set: 40 (C/N) 5 core atoms incl. MP2 sampling	[4]
1297	VN ₃ H	C-H _b	H	-	0	LDA*	64	Gaussian (<i>atom centered</i>)	Basis set: 28 (C) 40 (N) 5 core atoms incl. MP2 sampling	[4]
1310	VNH ⁰	C-H _b	H	-	1	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1310	VN ₂ H ⁺	C-H _b (b)	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1320	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]
1322	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]
1330	VNH ⁺	C-H _b	H	-	1/2	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1330	VNH ₂ ⁻	C-H _b (b)	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1330	VN ₂ H ⁰	C-H _b (b)	H	-	1/2	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1331	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 4x4x4 mesh	[1]
1333	VN ₃ H	C-H _b (b)	H	5 (0.8%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H)	[2]

										MP8 sampling	
1333	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	216	Gaussian (all electron)	Freq. calc. includes first 4 neighboring atoms MP 2x2x2 mesh	[1]	
1340	VNH ⁻	C-H _b	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1340	VN ₂ H ⁰	C-H _b (a)	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1347	BH ₁	C-H _b	H	60	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]	
1348	BH ₁	C-H _b	H	60	1	B3LYP**	216	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]	
1349	VH ₁	C-H _b	H	99	2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
1350	VH ₁ ⁻	C-H _b	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1350	VH ₂ ⁰	C-H _b (b)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1350	VN ₂ H ⁺	C-H _b (a)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1353	VH ₂	C-H _b (c)	H	2	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
1358	VH ₂	C-H _b (c)	H	61	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
1360	VN ₃ H	C-H _b	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1360	VH ₂	C-H _b (b)	H	70	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
1361	VN ₃ H	C-H _b	H	-	0	LDA*	64	Gaussian (atom centered)	Basis set: 40 (C/N) All atoms incl.	[4]	
1365	VN ₃ H	C-H _b	H	-	0	LDA*	216	Gaussian	MP2 sampling Basis set: 28 (C) 40 (N)	[4]	

1366	VN ₃ H	C-H _b	H	-	0	GGA*	64	(atom centered) All atoms incl. MP2 sampling Basis set: 40 (C/N)	[4]
1367	VN ₃ H	C-H _b	H	-	0	LDA*	64	(atom centered) All atoms incl. MP2 sampling Basis set: 28 (C) 40 (N)	[4]
1370	VH ₁ ⁺	C-H _b	H	-	0	PBE*	1000	(atom centered) All atoms incl. MP2 sampling Γ point sampling	[5]
1372	VNH ₂	C-H _b (c)	H	23 (4%)	1/2	B3LYP**	64	(all electron) All atoms incl. MP2 sampling Basis set: 6-21G (C/N) 6-31G (H)	[2]
1380	VH ₄	C-H _b (b)	H	-	0	PBE*	1000	(atom centered) All atoms incl. MP8 sampling Γ point sampling	[5]
1382	VH ₄	C-H _b (a)	H	233 (38%)	-	B3LYP**	64	(all electron) All atoms incl. Freq. calc. includes first only defect atoms MP 4x4x4 mesh	[1]
1384	VN ₃ H	C-H _b	H	-	0	GGA*	64	(atom centered) All atoms incl. Γ point sampling	[4]
1387	VH ₄	C-H _b (a)	H	0 (0%)	-	B3LYP**	216	(all electron) All atoms incl. Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]
1389	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	216	(all electron) All atoms incl. Freq. calc. includes first 12 neighboring atoms MP 2x2x2 mesh	[1]
1390	VH ₄	C-H _b (a)	H	-	0	PBE*	1000	(atom centered) All atoms incl. Γ point sampling	[5]
1391	VNH ₂	C-H _b (b)	H	87 (14%)	1/2	B3LYP**	64	(all electron) All atoms incl. MP2 sampling Basis set: 6-21G (C/N) 6-31G (H)	[2]
1392	VN ₂ H ₂	C-H _b (c)	H	8 (1%)	-	B3LYP**	64	(all electron) All atoms incl. MP8 sampling Basis set: 6-21G (C/N) 6-31G (H)	[2]
1394	VN ₄ H	C-H _b	H	-	-	LDA***	68	Planewave MP8 sampling Model 1 position	[8]

										MP 6x6x2 mesh	
1398	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	64	Gaussian (all electron)	Freq. calc. includes first 24 neighboring atoms MP 4x4x4 mesh	[1]	
1398	VN ₂ H ₂	C-H _b (b)	H	114 (18%)	-	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
1399	VH ₄	C-H _b (b)	H	0 (0%)	-	B3LYP**	216	Gaussian (all electron)	Freq. calc. includes first 24 neighboring atoms MP 2x2x2 mesh	[1]	
1400	NH ₁	C-H _b	H	-	-	LDF*	64	Gaussian	Atom and bond centered basis sets	[3]	
1400	VNH ⁻²	C-H _b	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1400	VH ₃ ⁺	C-H _b (c)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1400	VH ₄	C-H _b (b)	H	0	-	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
1404	NH ₁	C-H _s	H	-	-	LDA*	64	Gaussian (atom centered)	2-fold degenerate MP 2x2x2 mesh	[9]	
1407	BH ₁	C-H _b	H	115	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]	
1410	VH ₃ ⁰	C-H _b (b)	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
1411	BH ₁	C-H _b	H	115	1	B3LYP**	216	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]	
1411	VN ₃ H	C-H _b	H	240 (39%)	-	B3LYP**	216	Gaussian (all electron)	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]	
1414	VNH	C-H _b (b)	H	74 (12%)	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
1415	VN ₃ H	C-H _b	H	249 (41%)	-	B3LYP**	64	Gaussian (all electron)	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]	

1420	VH ₁	C-H _b (b)	H	32	1/2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
1421	VNH	C-H _b (a)	H	58 (9%)	1	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1422	VNH	C-H _b (b)	H	81 (13%)	0	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1423	VH ₄	C-H _b (a)	H	285 (46%)	-	B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 4x4x4 mesh	[1]
1424	VN ₂ H	C-H _b (b)	H	39 (6%)	1/2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1428	VH ₄	C-H _b (a)	H	292 (48%)	-	B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 2x2x2 mesh	[1]
1430	VNH ⁰	C-H _b	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1430	VH ₃ ⁺	C-H _b (b)	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1431	VNH ⁰	C-H _b	H	-		LDA*	216	Gaussian (<i>atom centered</i>)	Basis set: 28 (C/N) MP2 sampling	[4]
1440	VH ₃ ⁺	C-H _b (a)	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
1442	VN ₃ H	C-H _b	Ah	-		B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling C-H mode coupling	[10]
1446	VN ₃ H	C-H _b	Ah	-		B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling C-H mode coupling Anharmonicity by VSCF	[10]

1447	VN ₃ H	C-H _b	H	206 (34%)		B3LYP**	216	Gaussian (all electron)	Freq. calc. includes first 12 neighboring atoms MP 2x2x2 mesh	[1]
1448	VN ₃ H	C-H _b	H	16 (32%)		B3LYP**	32	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[10]
1450	VH ₃ ⁰	C-H _b (a)	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
1452	VNH ⁻	C-H _b	H	-		LDA*	216	Gaussian (atom centered)	Basis set: 28 (C/N) MP2 sampling	[4]
1452	VN ₃ H	C-H _b	H	213 (34%)		B3LYP**	64	Gaussian (all electron)	Freq. calc. includes first 12 neighboring atoms MP 4x4x4 mesh	[1]
1454	VN ₃ H	C-H _b	H	194 (31%)		B3LYP**	216	Gaussian (all electron)	Freq. calc. includes first 24 neighboring atoms MP 2x2x2 mesh	[1]
1459	VN ₃ H	C-H _b	H	202 (33%)		B3LYP**	64	Gaussian (all electron)	Freq. calc. includes first 24 neighboring atoms MP 4x4x4 mesh	[1]
1460	VNH ₃	C-H _b (b)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
1461	VN ₃ H	C-H _b (a)	H	205 (33%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1461	VN ₃ H	C-H _b	H	16 (32%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]
1461	VH ₂	C-H _b (b)	H	361	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
1463	VN ₃ H	C-H _b	H	16 (32%)		B3LYP**	128	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]
1470	VN ₂ H ⁻	C-H _b	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
1476	VN ₃ H	C-H _b	Ah	-		B3LYP**	64	Gaussian	Basis set: 6-21G (C/N)	[10]

									(all electron)	6-31G (H) Γ point sampling No C-H mode coupling Anharmonicity by VCI	
1478	VH ₄	C-H _b (a)	H	244 (39%)		B3LYP**	64	Gaussian (all electron)		Freq. calc. includes first 12 neighboring atoms MP 4x4x4 mesh	[1]
1479	VN ₂ H	C-H _b (a)	H	42 (7%)	1/2	B3LYP**	64	Gaussian (all electron)		Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1480	VNH ₃	C-H _b (a)	H	-	0	PBE*	1000	Gaussian (atom centered)		Γ point sampling	[5]
1484	VH ₄	C-H _b (a)	H	252 (41%)		B3LYP**	216	Gaussian (all electron)		Freq. calc. includes first 12 neighboring atoms MP 2x2x2 mesh	[1]
1486	VH ₄	C-H _b (a)	H	233 (38%)		B3LYP**	64	Gaussian (all electron)		Freq. calc. includes first 24 neighboring atoms MP 4x4x4 mesh	[1]
1487	VH ₁	C-H _b (a)	H	12	1/2	B3LYP**	64	Gaussian (all electron)		Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
1488	VH ₄	C-H _b (a)	H	231		B3LYP**	64	Gaussian (all electron)		Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
1489	VH ₃	C-H _b (b)	H	77	1/2	B3LYP**	64	Gaussian (all electron)		Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
1492	VH ₄	C-H _b (a)	H	239 (39%)		B3LYP**	216	Gaussian (all electron)		Freq. calc. includes first 24 neighboring atoms MP 2x2x2 mesh	[1]
1501	VNH	C-H _b (a)	H	17 (3%)	0	B3LYP**	64	Gaussian (all electron)		Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1520	VH ₂ ⁺	C-H _b	H	-	1/2	PBE*	1000	Gaussian (atom centered)		Γ point sampling	[5]
1520	VH ₃ ⁻	C-H _b (b)	H	-	0	PBE*	1000	Gaussian		Γ point sampling	[5]

											<i>(atom centered)</i>	
1529	VNH ₃	C-H _b (b)	H	189 (30%)		B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]		
1538	VH ₃	C-H _b (a)	H	104	1/2	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]		
1540	VH ₂ ⁰	C-H _b (a)	H	-	0	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1550	VH ₂ ⁰	C-H _b	H	-	1	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1550	VNH ₂ ⁺	C-H _b	H	-	0	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1560	VH ₃ ⁻	C-H _b (a)	H	-	0	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1580	VNH ₂ ⁰	C-H _b	H	-	1/2	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1584	VNH ₃	C-H _b (a)	H	159 (26%)		B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling 2-fold degenerate	[2]		
1586	NH ₁	C-H _b	Ah	20	1	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G Γ point sampling	[6]		
1589	VN ₄ H	C-H _b	H	-		LDA***	68	Planewave	Model 2 position MP 6x6x2 mesh	[8]		
1590	NH ₁	C-H _b	Ah	20	1	B3LYP**	216	Gaussian <i>(all electron)</i>	Basis set: 6-21G Γ point sampling	[6]		
1590	VH ₂ ⁻	C-H _b	H	-	1/2	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]		
1598	D ₁ ⁺	C-H _s (b)	H	-		LDF*	64	Gaussian	H ₁ = D (BC site) Atom and bond centered basis sets	[3]		
1616	VH ₂	C-H _b (a)	H	21	1	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]		

1620	VN ₂ H ₂	C-H _b	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
1627	VH ₂	C-H _b (a)	H	284	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[7]
1653	VNH ₂	C-H _b (a)	H	50 (8%)	1/2	B3LYP**	64	Gaussian (all electron)	Γ point sampling Basis set: 6-21G (C/N) 6-31G (H)	[2]
1680	VH ₂ ⁻²	C-H _b	H	-	0	PBE*	1000	Gaussian (atom centered)	MP8 sampling Γ point sampling	[5]
1680	VNH ₂ ⁻	C-H _b (a)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
1701	VN ₂ H ₂	C-H _b (a)	H	153 (25%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
1797	D ₁ ⁺	C-H _s (a)	H	-		LDF*	64	Gaussian	H ₁ = D (BC site) Atom and bond centered basis sets	[3]
1804	BH ₁	C-H _b	H	250	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]
1866	BH ₁	C-H _b	H	275	1	B3LYP**	216	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]
1952	D ₁ ⁻	C-H _s	H	-		LDF*	64	Gaussian	H ₁ = D (BC site) Atom and bond centered basis sets	[3]
1973	VNH ⁰	C-H _s	H	-	1	LDA*	64	Gaussian	¹³ C-D isotopes MP2 ³ sampling	[11]
1986	VNH ⁰	C-H _s	H	-	1	LDA*	64	Gaussian	¹² C-D isotopes MP2 ³ sampling	[11]
2026	VNH ⁺	C-H _s	H	-	1	LDA*	64	Gaussian	¹³ C-D isotopes MP2 ³ sampling	[11]
2038	VNH ⁺	C-H _s	H	-	1	LDA*	64	Gaussian	¹² C-D isotopes MP2 ³ sampling	[11]
2067	VNH ⁻	C-H _s	H	-	1	LDA*	64	Gaussian	¹³ C-D isotopes MP2 ³ sampling	[11]
2080	VNH ⁻	C-H _s	H	-	1	LDA*	64	Gaussian	¹² C-D isotopes	[11]

										MP2 ³ sampling
2084	D ₁ ⁰	C-H _s	H	-		LDF*	64	Gaussian	H ₁ = D (BC site) Atom and bond centered basis sets	[3]
2086	H ₁ ⁺	C-H _s (b)	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) Atom and bond centered basis sets	[3]
2207	VN ₃ H	C-H _s	H	-	0	LDA*	216	Gaussian (<i>atom centered</i>)	¹³ C-D isotopes Basis set: 28 (C) 40 (N) All atoms incl. MP2 sampling	[4]
2221	VN ₃ H	C-H _s	H	-	0	LDA*	216	Gaussian (<i>atom centered</i>)	¹² C-D isotopes Basis set: 28 (C) 40 (N) All atoms incl. MP2 sampling	[4]
2414	NH ₁	C-H _s	H	-		LDF*	64	Gaussian	¹² C-D isotopes Atom and bond centered basis sets	[3]
2450	VH ₁ ⁰	C-H _s	H	-	3/2	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
2450	VH ₁ ⁰	C-H _s	H	-	3/2	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[12]
2456	H ₁ ⁺	C-H _s (a)	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) Atom and bond centered basis sets	[3]
2470	VH ₁ ⁻³	C-H _s	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
2483	VH ₁	C-H _s	Ah	-	2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
2483	VH ₁	C-H _s	Ah	253	2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
2540	VH ₁ ⁻³	C-H _s	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[12]

2550	VNH ⁻²	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2571	H ₂	C-H _{sy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = D (BC site) H ₂ = D (AB site) MP 2x2x2 mesh	[9]
2580	VH ₁ ⁺	C-H _s	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]
2584	H ₂	C-H _{sy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = D (BC site) H ₂ = H (AB site) MP 2x2x2 mesh	[9]
2630	VN ₂ H ⁻	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2689	VNH ⁰	C-H _s	H	-	1	LDA*	64	Gaussian	¹³ C-H isotopes MP2 ³ sampling	[11]
2693	H ₂	C-H _{sy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = H (BC site) H ₂ = D (AB site) MP 2x2x2 mesh	[9]
2697	VNH ⁰	C-H _s	H	-	1	LDA*	64	Gaussian	MP2 ³ sampling	[11]
2700	VN ₂ H ⁻	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Basis set: 8-31G (C) 4-31G (N), 3-21G (H) Γ point sampling	[14]
2710	VH ₁ ⁻²	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]
2712	H ₂	C-H _{asy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = D (BC site) H ₂ = D (AB site) MP 2x2x2 mesh	[9]
2730	H ₁ ⁻	C-H _s	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) Atom and bond centered basis sets	[3]
2750	VH ₁ ⁻²	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2763	VNH ⁺	C-H _s	H	-	1	LDA*	64	Gaussian	¹³ C-H isotopes MP2 ³ sampling	[11]
2764	VH ₁	C-H _s	H	253	2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[7]

									Γ point sampling	
2770	VH ₂ ⁻²	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2771	VNH ⁺	C-H _s	H	-	1	LDA*	64	Gaussian	MP2 ³ sampling	[11]
2818	VH ₁	C-H _s	H	-	2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H)	[13]
2819	VNH ⁻	C-H _s	H	-	1	LDA*	64	Gaussian	Γ point sampling ¹³ C-H isotopes	[11]
2827	VNH ⁻	C-H _s	H	-	1	LDA*	64	Gaussian	MP2 ³ sampling MP2 ³ sampling	[11]
2850	VNH ⁰	C-H _{sy}	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2850	VNH ₂ ⁻	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2858	VNH ⁰	C-H _s	H	-	1	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
2866	VNH ⁻	C-H _s	H	-		LDA*	216	Gaussian (atom centered)	Basis set: 28 (C/N) MP2 sampling	[4]
2893	VH ₁	C-H _s	Ah	-	1/2	PBE**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H)	[13]
2894	VNH	C-H _s (a)	Ah	15 (2%)	1	B3LYP**	64	Gaussian (all electron)	Γ point sampling Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
2900	H ₁	C-H _s	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = H (BC site) MP 2x2x2 mesh	[9]
2919	H ₁ ⁰	C-H _s	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) Atom and bond centered basis sets	[3]
2928	VH ₁ ⁻	C-H _s	H	-		LDA*	64	Gaussian (atom centered)	MP 2x2x2 mesh	[9]
2930	VNH ⁻	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2941	VNH ⁻	C-H _s	H	-		GGA*	216	Gaussian	MP 2x2x2 mesh	[15]

2946	VH ₁	C-H _s	Ah	-	1/2	HSE06**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
2950	VNH ⁺	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
2952	VH ₁	C-H _s	Ah	-	1/2	PBE0**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
2970	VH ₁ ⁻	C-H _s	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]
2981	VH ₁	C-H _s	Ah	-	1/2	LDA**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
3000	VH ₁ ⁻	C-H _s	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]
3010	VH ₁ ⁻	C-H _s	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3015	VH ₁	C-H _s	Ah	77	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3015	VH ₁	C-H _s	Ah	-	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
3018	VN ₃ H	C-H _s	H	-	0	LDA*	64	Gaussian (atom centered)	Basis set: 28 (C) 40 (N) 5 core atoms incl. MP2 sampling	[4]
3025	VN ₃ H	C-H _s	H	-	0	LDA*	216	Gaussian (atom centered)	¹³ C-H isotopes Basis set: 28 (C) 40 (N) All atoms incl. MP2 sampling	[4]
3028	VN ₃ H	C-H _s	H	-	0	LDA*	64	Gaussian (atom centered)	Basis set: 28 (C) 40 (N) All atoms incl. MP2 sampling	[4]
3034	VN ₃ H	C-H _s	H	-	0	LDA*	216	Gaussian (atom centered)	Basis set: 28 (C) 40 (N) All atoms incl. MP2 sampling	[4]

3037	VN ₃ H	C-H _s	H	-	0	LDA*	64	Gaussian (atom centered)	Basis set: 40 (C/N) All atoms incl. MP2 sampling	[4]
3039	VN ₃ H	C-H _s	H	-	0	LDA*	216	Gaussian (atom centered)	Basis set: 40 (C/N) 5 core atoms incl. MP2 sampling	[4]
3040	VH ₂ ⁰	C-H _{asy}	H	-	1	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3040	VN ₂ H ⁰	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3040	VH ₁ ⁰	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]
3050	VN ₂ H ⁰	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Basis set: 8-31G (C) 4-31G (N), 3-21G (H) Γ point sampling	[14]
3050	VH ₂ ⁻²	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3050	VN ₂ H ⁺	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3054	VN ₃ H	C-H _s	Ah	-		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling C-H mode coupling Anharmonicity by VSCF	[10]
3060	VH ₂ ⁰	C-H _{asy}	H	-	1	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3065	VN ₂ H	C-H _s (a)	Ah	122 (20%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3069	VNH	C-H _s (a)	Ah	129 (21%)	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3090	VH ₃ ⁻	C-H _{asy} (b)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3094	VN ₃ H	C-H _s	Ah	-		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]

3095	VN ₄ H	C-H _s	H	-		LDA***	68	Planewave	C-H mode coupling Anharmonicity by VCI Model 2 position MP 6x6x2 mesh	[8]
3096	VNH	C-H _s (a)	H	7 (1%)	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3100	VH ₂ ⁺	C-H _{asy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3100	VNH ₂ ⁻	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3114	VH ₁ ⁰	C-H _s	H	-		LDA*	64	Gaussian (atom centered)	MP 2x2x2 mesh	[9]
3118	VH ₂ ⁻	C-H _{asy}	H	-		GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3120	VH ₂ ⁻	C-H _{asy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3120	VH ₃ ⁻	C-H _{asy} (a)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3120	VN ₃ H	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3122	VNH ⁰	C-H _s	H	-		LDA*	216	Gaussian (atom centered)	Basis set: 28 (C/N) MP2 sampling	[4]
3122	VN ₃ H	C-H _s	Ah	-		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling No C-H mode coupling Anharmonicity by VCI	[10]
3125	VN ₃ H	C-H _s	H	-	0	GGA*	64	Gaussian (atom centered)	Basis set: 40 (C/N) All atoms incl. MP2 sampling	[4]
3130	VH ₁ ⁰	C-H _s	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3132	VN ₃ H	C-H _s	Ah	-	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]
3133	VN ₃ H	C-H _s (a)	Ah	621 (100%)		B3LYP	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[2]

										MP8 sampling	
3153	VH ₁	C-H _s	H	-	1/2	PBE**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]	
3174	VH ₁	C-H _s	H	-	1/2	HSE06**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]	
3176	VH ₁	C-H _s	H	-	1/2	PBE0**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]	
3180	VNH ⁰	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
3188	VH ₁	C-H _s	H	-	1/2	LDA**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]	
3190	VNH ⁰	C-H _s	H	-	0	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]	
3193	VH ₁	C-H _s	H	77	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
3196	VN ₃ H	C-H _s	H	-	0	GGA*	64	Gaussian (atom centered)	Basis set: 40 (C/N) All atoms incl. Γ point sampling	[4]	
3200	VNH ₂ ⁺	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
3210	VH ₁ ⁺	C-H _s	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[12]	
3213	VN ₂ H	C-H _s (a)	H	122 (20%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
3221	VN ₄ H	C-H _s	H	-		LDA***	68	Planewave	Model 1 position MP 6x6x2 mesh	[8]	
3224	VNH	C-H _s (a)	H	129 (21%)	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
3230	VNH ₂ ⁰	C-H _{asy}	H	-	1/2	PBE*	1000	Gaussian	Γ point sampling	[5]	

										<i>(atom centered)</i>	
3231	VH ₁	C-H _s	H	-	1/2	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]	
3249	VN ₃ H	C-H _s	H	50 (100%)		B3LYP**	32	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]	
3250	VN ₃ H	C-H _s (a)	H	621 (100%)		B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
3250	VN ₃ H	C-H _s	H	50 (100%)		B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]	
3250	VN ₃ H	C-H _s	H	619 (100%)		B3LYP**	64	Gaussian <i>(all electron)</i>	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]	
3251	VN ₃ H	C-H _s	H	50 (100%)		B3LYP**	128	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[10]	
3253	VH ₂	C-H _{asy}	Ah	29	1	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
3262	VN ₃ H	C-H _s	H	608 (100%)		B3LYP**	216	Gaussian <i>(all electron)</i>	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]	
3271	VN ₃ H	C-H _s	H	-	1	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G Γ point sampling	[6]	
3275	VH ₂	C-H _{asy}	H	29	1	B3LYP**	64	Gaussian <i>(all electron)</i>	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
3309	NH ₁	C-H _s	H	-		LDA*	64	Gaussian <i>(atom centered)</i>	MP 2x2x2 mesh	[9]	
3310	VH ₁ ⁺	C-H _s	H	-	0	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]	
3310	VH ₂ ⁰	C-H _{sy}	H	-	1	PBE*	1000	Gaussian <i>(atom centered)</i>	Γ point sampling	[5]	

3318	NH ₁	C-H _s	H	-		LDF*	64	Gaussian	¹³ C-H isotopes Atom and bond centered basis sets	[3]
3320	VN ₂ H ₂	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Gaussian basis set	[5]
3324	NH ₁	C-H _s	H	-		LDF*	64	Gaussian	Atom and bond centered basis sets	[3]
3330	VH ₂ ⁻	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3337	VH ₂ ⁰	C-H _{sy}	H	-	1	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3339	VH ₂ ⁻	C-H _{sy}	H	-		GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3350	VH ₂ ⁰	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3356	VH ₂ ⁰	C-H _{asy}	H	-	0	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3370	VN ₂ H ₂ ⁰	C-H _{asy}	H	-		PBE*	1000	Gaussian (atom centered)	Basis set: 8-31G (C) 4-31G (N), 3-21G (H) Γ point sampling	[14]
3370	VH ₂ ⁺	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3378	VH ₂	C-H _{asy}	Ah	395	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3394	BH ₁	C-H _s	Ah	-	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]
3402	VNH ₂	C-H _s (b)	Ah	88 (14%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3410	VNH ₂ ⁺	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3417	VNH ₂	C-H _s (b)	H	88 (14%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3408	NH ₁	C-H _s	Ah	-	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]

3420	VNH ₂ ⁰	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3420	VH ₃ ⁺	C-H _{asy} (b)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3426	VH ₂	C-H _{asy}	H	395	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[7]
3428	VH ₁	C-H _s	Ah	-	1/2	HF**	64	Gaussian (all electron)	Γ point sampling Basis set: 6-21G (C/N) 6-31G ^(*) (H)	[13]
3430	VH ₃ ⁻	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3450	VH ₃ ⁺	C-H _{asy} (a)	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3450	VH ₃ ⁰	C-H _{asy} (b)	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3455	BH ₁	C-H _s	H	-	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G Γ point sampling	[6]
3460	VH ₃ ⁰	C-H _{asy} (a)	H	-	1/2	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3469	VN ₂ H ₂	C-H _{asy} (b)	H	346 (56%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[2]
3470	VN ₂ H ₂	C-H _s (b)	Ah	346 (56%)		B3LYP**	64	Gaussian (all electron)	MP8 sampling Basis set: 6-21G (C/N) 6-31G (H)	[2]
3471	NH ₁	C-H _s	H	-	1	B3LYP**	64	Gaussian (all electron)	Γ point sampling Basis set: 6-21G	[6]
3477	VH ₂	C-H _{sy}	Ah	2	1	B3LYP**	64	Gaussian (all electron)	Γ point sampling Basis set: 6-21G (C/N) 6-31G (H)	[7]
3490	VN ₂ H ₂	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3511	H ₂	C-H _{sy}	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) H ₂ = H (AB site) Atom and bond centered	[3]

										basis sets
3520	H ₂	C-H _{sy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = H (BC site) H ₂ = H (AB site) MP 2x2x2 mesh	[9]
3520	VH ₂ ⁰	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3525	VH ₂ ⁰	C-H _{sy}	H	-	0	GGA*	216	Gaussian	MP 2x2x2 mesh	[15]
3526	VH ₂	C-H _{sy}	H	2	1	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3540	VN ₂ H ₂ ⁰	C-H _{sy}	H	-		PBE*	1000	Gaussian (atom centered)	Basis set: 8-31G (C) 4-31G (N), 3-21G (H) Γ point sampling	[14]
3552	VH ₂	C-H _{sy}	Ah	571	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3568	VH ₁	C-H _s	H	-	1/2	HF**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G ^(*) (H) Γ point sampling	[13]
3570	VNH ₃	C-H _{asy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]
3580	VNH ₂	C-H _s (a)	Ah	52 (8%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3584	H ₂	C-H _{asy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = H (BC site) H ₂ = D (AB site) MP 2x2x2 mesh	[9]
3606	VH ₂	C-H _{sy}	H	571	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3615	VNH ₂	C-H _s (a)	H	52 (8%)	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3641	VN ₂ H ₂	C-H _s (a)	Ah	185 (30%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H)	[2]

										MP8 sampling	
3651	VH ₃	C-H _{asy}	H	0	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
3653	VH ₃	C-H _{asy}	Ah	0	1/2	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]	
3664	VN ₂ H ₂	C-H _s (a)	H	185 (30%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[2]	
3700	VH ₃ ⁺	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	MP8 sampling Γ point sampling	[5]	
3704	VNH ₃	C-H _s (b)	H	189 (30%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
3710	VH ₃ ⁰	C-H _{sy}	H	-	1/2	PBE*	1000	Gaussian (atom centered)	2-fold degenerate Γ point sampling	[5]	
3720	H ₂	C-H _{asy}	H	-		LDA*	64	Gaussian (atom centered)	H ₁ = D (BC site) H ₂ = H (AB site) MP 2x2x2 mesh	[9]	
3725	VNH ₃	C-H _s (b)	Ah	189 (30%)		B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]	
3741	H ₂	C-H _{asy}	H	-		LDA*	64	Gaussian (atom centered)	2-fold degenerate H ₁ = H (BC site) H ₂ = H (AB site) MP 2x2x2 mesh	[9]	
3790	VNH ₃	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (atom centered)	Γ point sampling	[5]	
3853	VH ₄	C-H _s (b)	H	14 (2%)		B3LYP**	64	Gaussian (all electron)	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]	
3868	VH ₄	C-H _s (b)	H	12 (2%)		B3LYP**	216	Gaussian (all electron)	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]	

3882	H ₂	C-H _{asy}	H	-		LDF*	64	Gaussian	H ₁ = H (BC site) H ₂ = D (AB site) Atom and bond centered basis sets	[3]
3908	VH ₃	C-H _{sy}	H	1	1/2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3943	VNH ₃	C-H _s (a)	H	56 (9%)		B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
3953	VH ₃	C-H _{sy}	Ah	1	1/2	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3974	VH ₄	C-H _s (b)	H	4 (0.6%)		B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 4x4x4 mesh	[1]
3974	VH ₄	C-H _{asy}	H	4		B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
3989	VH ₄	C-H _s (b)	H	3 (0.5%)		B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes first 4 neighboring atoms MP 2x2x2 mesh	[1]
4000	VNH ₃	C-H _s (a)	Ah	56 (9%)		B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) MP8 sampling	[2]
4037	VH ₄	C-H _{asy}	Ah	5	0	B3LYP**	64	Gaussian (<i>all electron</i>)	Basis set: 6-21G (C/N) 6-31G (H) Γ point sampling	[7]
4120	VH ₄	C-H _{sy}	H	-	0	PBE*	1000	Gaussian (<i>atom centered</i>)	Γ point sampling	[5]
4199	VH ₄	C-H _s (a)	H	0 (0%)		B3LYP**	64	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 4x4x4 mesh	[1]
4221	VH ₄	C-H _s (a)	H	0 (0%)		B3LYP**	216	Gaussian (<i>all electron</i>)	Freq. calc. includes only defect atoms MP 2x2x2 mesh	[1]

4276	VH ₄	C-H _s (a)	H	0 (0%)	B3LYP**	64	Gaussian (all electron)	Freq. calc. includes first 4 [1] neighboring atoms MP 4x4x4 mesh
4276	VH ₄	C-H _{sy}	H	0	B3LYP**	64	Gaussian (all electron)	Basis set: 6-21G (C/N) [7] 6-31G (H) Γ point sampling
4298	VH ₄	C-H _s (a)	H	0 (0%)	B3LYP**	216	Gaussian (all electron)	Freq. calc. includes first 4 [1] neighboring atoms MP 2x2x2 mesh

The defect electrical charge q (e.g. VN^q), and the harmonic (H) or anharmonic (Ah) calculated frequencies are only included if explicitly specified in the corresponding reference.

Where more than one H-atom is present, both symmetric (C-H_{sy}) and anti-symmetric (C-H_{asy}) stretching modes are expected and reported only if explicitly specified in the corresponding reference.

Calculated peak intensities are reported in km/mol. In cases where the VN₃H defect is simulated, relative intensities were normalized and reported (as %) in comparison to the VN₃H C-H stretching mode, which is always the most intense peak observed in experiment.

Isotopes ¹²C, ¹H and ¹⁴N is assumed unless otherwise specified.

Total spin quantum number = S ; $S = 0$ (singlet), $S = 1$ (triplet), $S = 3/2$ (quartet), $S = 1/2$ (doublet), $S = 2$ (quadruplet).

Monkhorst-Pack sampling scheme denoted as MP n , where a mesh of $n \times n \times n$ points (k) is used to sample the Brillouin Zone. Point symmetry of a given defect may reduce k .

AIMPRO* (*ab initio* modelling PROgram), **Crystal**** and **Quantum ESPRESSO***** density-functional modelling programs indicated in **Functional** column.

Note that many bands have calculated intensities significantly less than the intensity of the 3107cm⁻¹ band and are unlikely to be observed in experimental data.

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